

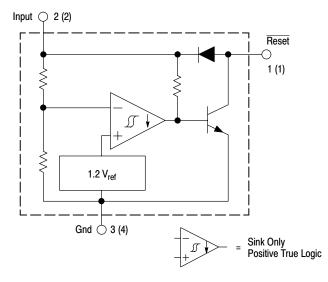
Undervoltage Sensing Circuit

The MC34064 is an undervoltage sensing circuit specifically designed for use as a reset controller in microprocessor-based systems. It offers the designer an economical solution for low voltage detection with a single external resistor. The MC34064 features a trimmed-in-package bandgap reference, and a comparator with precise thresholds and built-in hysteresis to prevent erratic reset operation. The open collector reset output is capable of sinking in excess of 10 mA, and operation is guaranteed down to 1.0 V input with low standby current. These devices are packaged in 3-pin TO-226AA, 8-pin SO-8 and Micro-8 surface mount packages.

Applications include direct monitoring of the 5.0 V MPU/logic power supply used in appliance, automotive, consumer and industrial equipment.

- Trimmed-In-Package Temperature Compensated Reference
- Comparator Threshold of 4.6 V at 25°C
- Precise Comparator Thresholds Guaranteed Over Temperature
- Comparator Hysteresis Prevents Erratic Reset
- Reset Output Capable of Sinking in Excess of 10 mA
- Internal Clamp Diode for Discharging Delay Capacitor
- Guaranteed Reset Operation with 1.0 V Input
- Low Standby Current
- Economical TO–226AA, SO–8 and Micro–8 Surface Mount Packages

Representative Block Diagram



Pin numbers adjacent to terminals are for the 3–pin TO–226AA package. Pin numbers in parenthesis are for the 8–lead packages.

This device contains 21 active transistors.

MC34064 MC33064

UNDERVOLTAGE SENSING CIRCUIT

SEMICONDUCTOR TECHNICAL DATA

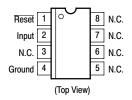


D SUFFIXPLASTIC PACKAGE
CASE 751
(SO-8)



DM SUFFIX
PLASTIC PACKAGE
CASE 846A
(Micro-8)





ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC34064D-5		SO-8
MC34064DM-5	$T_A = 0^\circ \text{ to } +70^\circ \text{C}$	Micro-8
MC34064P-5		TO-226AA
MC33064D-5		SO-8
MC33064DM-5	$T_A = -40^{\circ} \text{ to } +85^{\circ}\text{C}$	Micro-8
MC33064P-5		TO-226AA

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Input Supply Voltage	V _{in}	-1.0 to 10	V
Reset Output Voltage	Vo	10	V
Reset Output Sink Current (Note 1)	I _{Sink}	Internally Limited	mA
Clamp Diode Forward Current, Pin 1 to 2 (Note 1)	I _F	100	mA
Power Dissipation and Thermal Characteristics P Suffix, Plastic Package Maximum Power Dissipation @ T _A = 25°C Thermal Resistance, Junction—to—Air D Suffix, Plastic Package Maximum Power Dissipation @ T _A = 25°C Thermal Resistance, Junction—to—Air DM Suffix, Plastic Package Maximum Power Dissipation @ T _A = 25°C Thermal Resistance, Junction—to—Air	P _D R _{θJA} P _D R _{θJA} P _D R _{θJA}	625 200 625 200 520 240	mW °C/W mW °C/W mW
Operating Junction Temperature	TJ	+150	°C
Operating Ambient Temperature MC34064 MC33064	T _A	0 to +70 -40 to +85	°C
Storage Temperature Range	T _{stg}	-65 to +150	°C

NOTE: ESD data available upon request.

ELECTRICAL CHARACTERISTICS (For typical values $T_A = 25^{\circ}C$, for min/max values T_A is the operating ambient temperature range that applies [Notes 2 and 3] unless otherwise noted.)

that applies [Notes 2 and 3] unless otherwise noted.)		1	1	1	1
Characteristics	Symbol	Min	Тур	Max	Unit
COMPARATOR					
Threshold Voltage High State Output (V _{in} Increasing) Low State Output (V _{in} Decreasing) Hysteresis	V _{IH} V _{IL} V _H	4.5 4.5 0.01	4.61 4.59 0.02	4.7 4.7 0.05	V
RESET OUTPUT	•				
Output Sink Saturation $(V_{in} = 4.0 \text{ V}, I_{Sink} = 8.0 \text{ mA})$ $(V_{in} = 4.0 \text{ V}, I_{Sink} = 2.0 \text{ mA})$ $(V_{in} = 1.0 \text{ V}, I_{Sink} = 0.1 \text{ mA})$	V _{OL}	- - -	0.46 0.15 -	1.0 0.4 0.1	V
Output Sink Current (V _{in} , Reset = 4.0 V)	I _{Sink}	10	27	60	mA
Output Off-State Leakage (V _{in} , Reset = 5.0 V)	Іон	-	0.02	0.5	μΑ
Clamp Diode Forward Voltage, Pin 1 to 2 (I _F = 10 mA)	V _F	0.6	0.9	1.2	V
TOTAL DEVICE	·	•		•	
Operating Input Voltage Range	V _{in}	1.0 to 6.5	_	_	V
Quiescent Input Current (V _{in} = 5.0 V)	I _{in}	_	390	500	μΑ

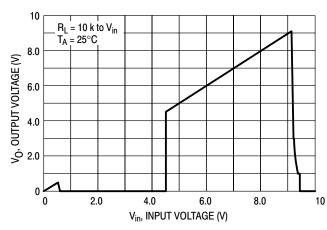


Figure 1. Reset Output Voltage versus Input Voltage

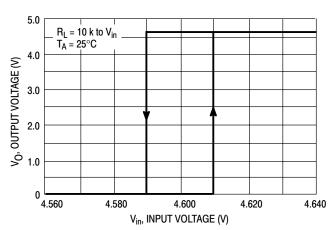


Figure 2. Reset Output Voltage versus Input Voltage

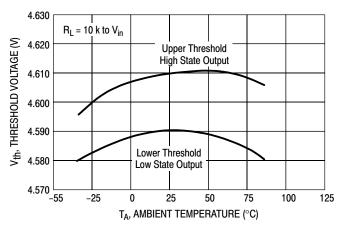


Figure 3. Comparator Threshold Voltage versus Temperature

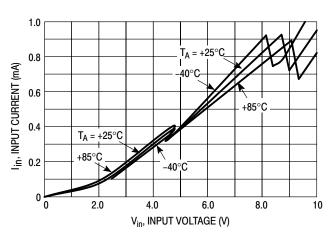


Figure 4. Input Current versus Input Voltage

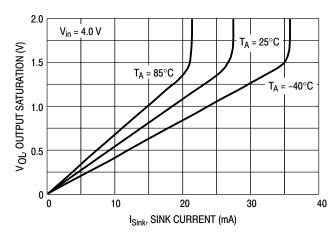


Figure 5. Reset Output Saturation versus Sink Current

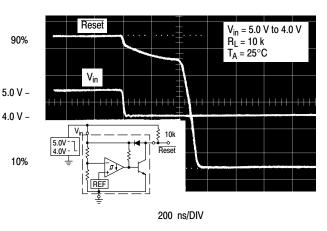


Figure 6. Reset Delay Time

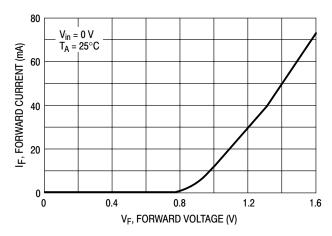


Figure 7. Clamp Diode Forward Current versus Voltage

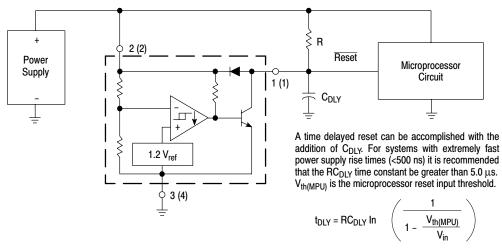
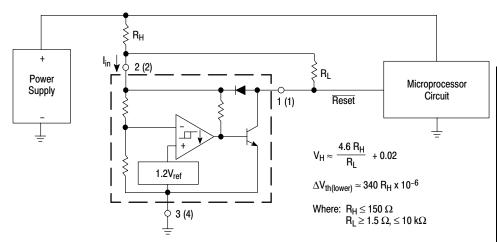


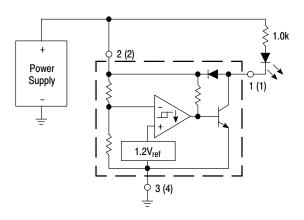
Figure 8. Low Voltage Microprocessor Reset



Comparator hysteresis can be increased with the addition of resistor $R_H.$ The hysteresis equation has been simplified and does not account for the change of input current l_{in} as V_{CC} crosses the comparator threshold (Figure 4). An increase of the lower threshold $\Delta V_{th(lower)}$ will be observed due to l_{in} which is typically 340 μA at 4.59 V. The equations are accurate to $\pm 10\%$ with R_H less than 150 Ω and R_L between 1.5 $k\Omega$ and 10 $k\Omega$.

Test Data					
V _H (mV)	ΔV_{th} (mV)	R _H (Ω)	R _L (kΩ)		
20	0	0	0		
51	3.4	10	1.5		
40	6.8	20	4.7		
81	6.8	20	1.5		
71	10	30	2.7		
112	10	30	1.5		
100	16	47	2.7		
164	16	47	1.5		
190	34	100	2.7		
327	34	100	1.5		
276	51	150	2.7		
480	51	150	1.5		

Figure 9. Low Voltage Microprocessor Reset with Additional Hysteresis



2 (2)

1 (1)

Solar Cells

3 (4)

Figure 10. Voltage Monitor

Figure 11. Solar Powered Battery Charger

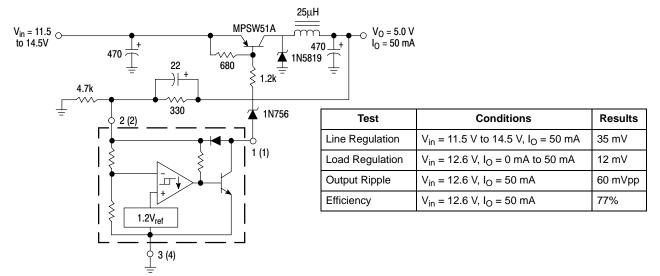
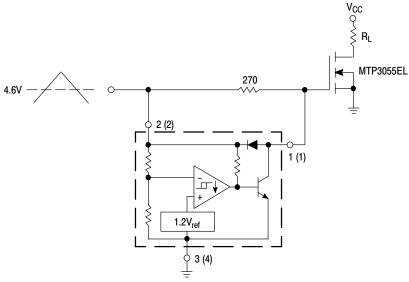


Figure 12. Low Power Switching Regulator



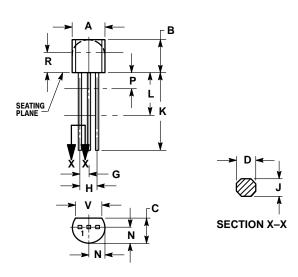
Overheating of the logic level power MOSFET due to insufficient gate voltage can be prevented with the above circuit. When the input signal is below the 4.6 V threshold of the MC34064, its output grounds the gate of the L^2 MOSFET.

Figure 13. MOSFET Low Voltage Gate Drive Protection

PACKAGE DIMENSIONS

P SUFFIX

PLASTIC PACKAGE CASE 29-11 (TO-226AA) **ISSUE AL**

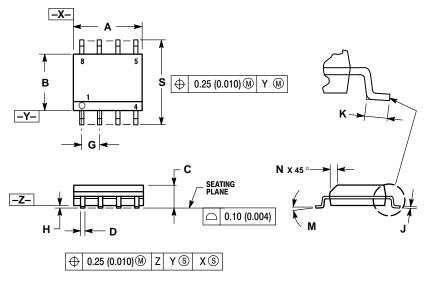


- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: INCH.
 3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
 4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN MAX	
Α	0.175	0.205	4.45	5.20
В	0.170	0.210	4.32	5.33
С	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
Н	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500		12.70	
L	0.250		6.35	
N	0.080	0.105	2.04	2.66
P		0.100		2.54
R	0.115		2.93	
٧	0.135		3.43	

D SUFFIX PLASTIC PACKAGE

CASE 751-07 (SO-8)ISSUE W



- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
- 4. MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER
- SIDE.

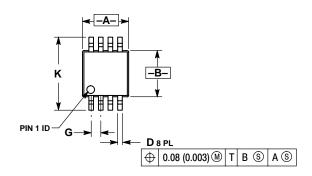
 5. DIMENSION D DOES NOT INCLUDE DAMBAR
 PROTRUSION. ALLOWABLE DAMBAR
 PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.

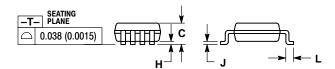
	MILLIMETERS		INCHES		
DIM	MIN	MAX	MIN	MAX	
Α	4.80	5.00	0.189	0.197	
В	3.80	4.00	0.150	0.157	
С	1.35	1.75	0.053	0.069	
D	0.33	0.51	0.013	0.020	
G	1.27 BSC		0.050 BSC		
Н	0.10	0.25	0.004	0.010	
J	0.19	0.25	0.007	0.010	
K	0.40	1.27	0.016 0.050		
M	0 °	8 °	0 °	8 °	
N	0.25	0.50	0.010	0.020	
S	5.80	6.20	0.228	0.244	

PACKAGE DIMENSIONS

DM SUFFIX

PLASTIC PACKAGE CASE 846A-02 (Micro-8) **ISSUE** É





- NOTES:
 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 2. CONTROLLING DIMENSION: MILLIMETER.
 3. DIMENSION A DOES NOT INCLUDE MOLD FLASH, PROTRUSIONS OR GATE BURRS. MOLD FLASH, PROTRUSIONS OR GATE BURRS SHALL NOT EXCEED 0.15 (0.006) PER SIDE.
 4. DIMENSION B DOES NOT INCLUDE INTERLEAD FLASH OR PROTRUSION. INTERLEAD FLASH OR PROTRUSION SHALL NOT EXCEED 0.25 (0.010) PER SIDE.

	MILLIN	IETERS	INCHES	
DIM	MIN MAX		MIN	MAX
Α	2.90	3.10	0.114	0.122
В	2.90	3.10	0.114	0.122
С		1.10		0.043
D	0.25	0.40	0.010	0.016
G	0.65	BSC	0.026	BSC
Н	0.05	0.15	0.002	0.006
J	0.13	0.23	0.005	0.009
K	4.75	5.05	0.187	0.199
L	0.40	0.70	0.016	0.028

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